MBR30H90PT, MBR30H100PT

Vishay General Semiconductor

HALOGEN

FREE

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)} 2 x 15 A					
V_{RRM}	90 V, 100 V				
I _{FSM}	265 A				
V_{F}	0.67 V				
I _R	5.0 μA				
T _J max.	175 °C				
Package TO-247AD 3L					
Circuit configuration	Common cathode				

FEATURES

- Power pack
- · Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max., 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - RoHS-compliant, halogen-free, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102
M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR30H90PT MBR30H100PT		UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	90	100	V	
Working peak reverse voltage		V_{RWM}	90 100		V	
Maximum DC blocking voltage		V_{DC}	90	100	V	
Maximum average forward rectified current	total device	1	30		Α	
	per diode	I _{F(AV)}	1	5		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	265		А	
Peak repetitive reverse surge current at t_p = 2 μ s, 1 kHz per diode		I _{RRM}	1.0		А	
Non-repetitve avalanche energy (I _{AS} = 0.5 A, L = 60 mH) per diode		E _{AS}	7.5		mJ	
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature ra	ange	T _J , T _{STG}	-65 to +175		°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MBR30H90PT	MBR30H100PT	UNIT	
	V _F ⁽¹⁾	I _F = 15 A	T _J = 25 °C	0.82		V	
Maximum instantaneous forward voltage per diode		$I_F = 15 A$	T _J = 125 °C	0.67			
		I _F = 30 A	T _J = 25 °C	0.	.93		
		$I_F = 30 \text{ A}$	T _J = 125 °C	0.	80		
Maximum instantaneous reverse current at	I _R ⁽¹⁾		T _J = 25 °C	5	.0	μΑ	
rated DC blocking voltage per diode	'R''		T _J = 125 °C	6	.0	mA	

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL MBR30H90PT MBR30H100PT UNIT				
Thermal resistance, junction to case per diode	$R_{ heta JC}$	1.6		°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-247AD 3L	MBR30H100PT-M3/P	5.83	Р	25/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

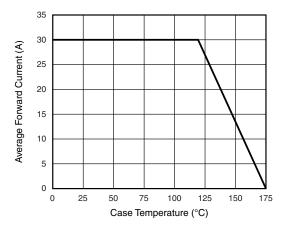


Fig. 1 - Forward Derating Curve

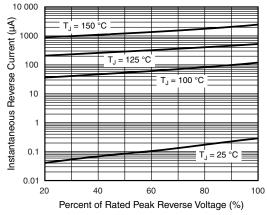


Fig. 3 - Typical Reverse Characteristics Per Diode

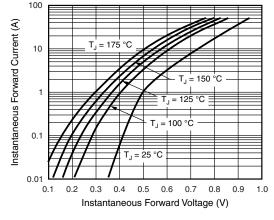


Fig. 2 - Typical Instantaneous Forward Characteristics Per Diode

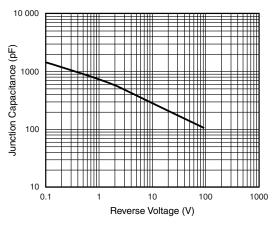
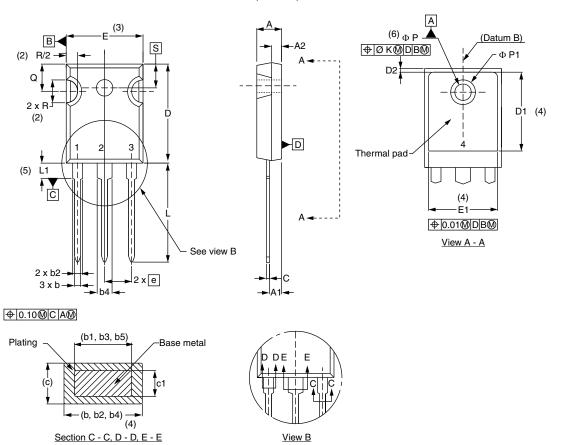


Fig. 4 - Typical Junction Capacitance Per Diode

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PACKAGE OUTLINE DIMENSIONS in millimeters (inches) TO-247AD 3L



SYMBOL	MILLIMETERS		INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	5.46 BSC		BSC	
ØΚ	0.2	254	0.0)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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